



Features

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# **TSM100N06** 60V N-Channel Power MOSFET

# TO-220

Advanced Trench Technology

Low Crss typical @ 339pF (Typ.)

Note: "G" denote for Halogen Free Product

Low gate charge typical @ 81nC (Typ.)

Low R<sub>DS(ON)</sub> 6.7mΩ (Max.)

**Ordering Information** 

Part No.

TSM100N06CZ C0G

- Pin Definition:
- 1. Gate
- 2. Drain 3. Source

#### PRODUCT SUMMARY

V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (mΩ)	I <sub>D</sub> (A)
60	6.7 @ V <sub>GS</sub> =10V	100

#### **Block Diagram**

# Gate O

N-Channel MOSFET

#### Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Package

TO-220

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	60	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	V	
	T <sub>C</sub> =25℃		100 <sup>(3)</sup>	0	
Continuous Drain Current	T <sub>C</sub> =70°C		80		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	14	A	
	T <sub>A</sub> =70°C		11		
Drain Current-Pulsed Note 1		I <sub>DM</sub>	400	А	
Avalanche Current, L=0.1mH		I <sub>AS</sub>	71	А	
Avalanche Energy, L=0.1mH		$E_{AS},E_{AR}$	400	mJ	
	T <sub>C</sub> =25°C		167		
Movimum Dower Dissinction	T <sub>C</sub> =70°C		107	147	
Maximum Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2	W	
	T <sub>A</sub> =70°C		1.3		
Storage Temperature Range		T <sub>STG</sub>	-55 to +150	°C	
Operating Junction Temperature Range		TJ	-55 to +150	°C	

Packing

50pcs / Tube

\* Limited by maximum junction temperature

#### **Thermal Performance**

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Case	R⊖ <sub>JC</sub>	0.8	°C/W
Thermal Resistance - Junction to Ambient	RƏ <sub>JA</sub>	62.5	°C/W

Notes: Surface mounted on FR4 board t  $\leq$  10sec



#### **Electrical Specifications** (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = 250uA$	BV <sub>DSS</sub>	60			V
Drain-Source On-State Resistance	$V_{GS} = 10V, I_{D} = 30A$	R <sub>DS(ON)</sub>		5.7	6.7	mΩ
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 uA$	V <sub>GS(TH)</sub>	2	3	4	V
Zero Gate Voltage Drain Current	$V_{DS} = 48V, V_{GS} = 0V$	I <sub>DSS</sub>			1	uA
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Dynamic		-				-
Total Gate Charge	$V_{DS} = 30V, I_D = 30A,$ $V_{GS} = 10V$	Qg		81		nC
Gate-Source Charge		Q <sub>gs</sub>		23		
Gate-Drain Charge		Q <sub>gd</sub>		24		
Input Capacitance	$V_{DS} = 30V, V_{GS} = 0V,$	C <sub>iss</sub>		4382		pF
Output Capacitance		C <sub>oss</sub>		668		
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		339		
Switching						
Turn-On Delay Time		t <sub>d(on)</sub>		25		
Turn-On Rise Time	$V_{GS} = 10V, V_{DS} = 30V,$	t <sub>r</sub>		19		
Turn-Off Delay Time	$R_{G} = 3.3\Omega$	t <sub>d(off)</sub>		85		nS
Turn-Off Fall Time		t <sub>f</sub>		43		
Drain-Source Diode Characteristics and Maximum Rating						
Drain-Source Diode Forward Voltage	V <sub>GS</sub> =0V, I <sub>S</sub> =20A	V <sub>SD</sub>	-	0.8	1.3	V
Reverse Recovery Time	I <sub>S</sub> = 30A, T <sub>J</sub> =25 °C	t <sub>fr</sub>		36		nS
Reverse Recovery Charge	dl/dt = 100A/us	Q <sub>fr</sub>		53		nC

Notes:

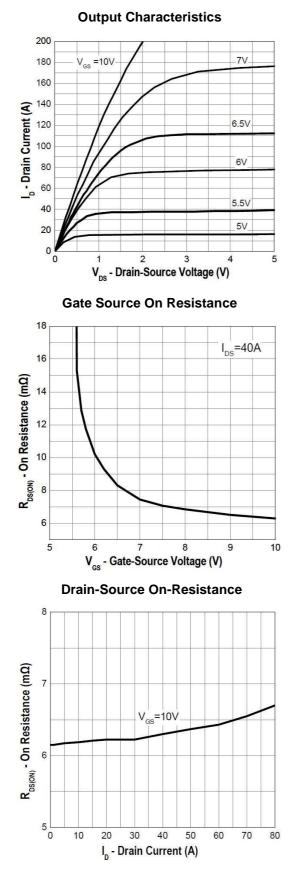
1. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

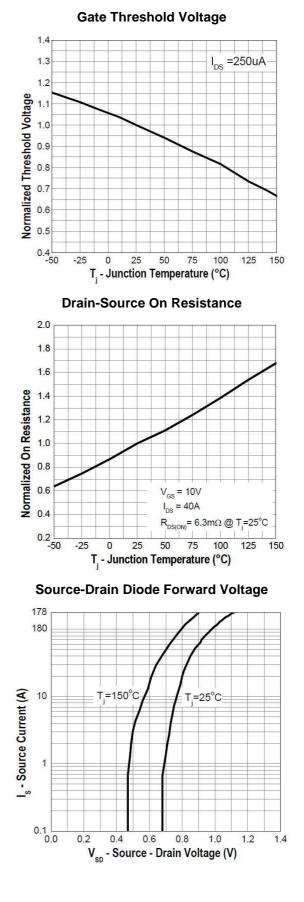
2.  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\Theta JC}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design.  $R_{\Theta JA}$  shown below for single device operation on FR-4 in still air

3. Calculated continuous current based on maximum allowable junction temperature, Package limitation current is 75A



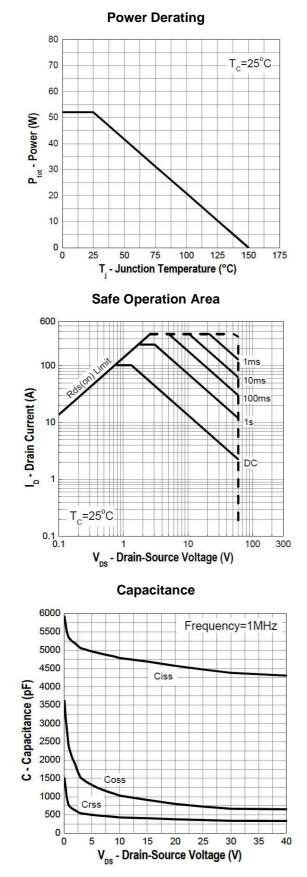
#### Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

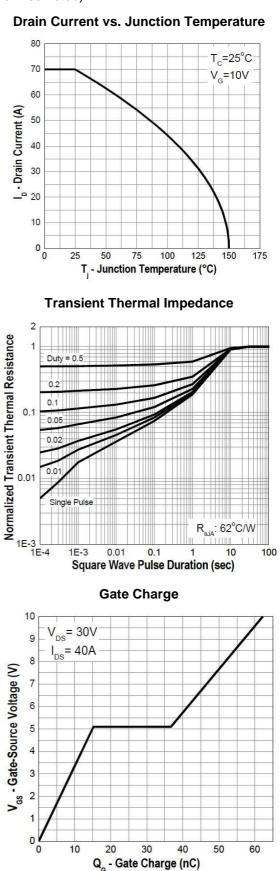






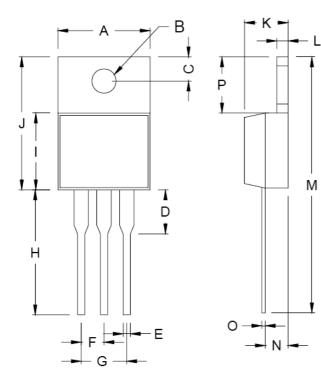
#### Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)







# **TO-220 Mechanical Drawing**



	TO-220 DIMENSION						
DIM	MILLIMETERS		INC	HES			
DIIVI	MIN	MAX	MIN	MAX			
А	10.000	10.500	0.394	0.413			
В	3.740	3.910	0.147	0.154			
С	2.440	2.940	0.096	0.116			
D	-	6.350	-	0.250			
Е	0.381	1.106	0.015	0.040			
F	2.345	2.715	0.092	0.058			
G	4.690	5.430	0.092	0.107			
Н	12.700	14.732	0.500	0.581			
J	14.224	16.510	0.560	0.650			
K	3.556	4.826	0.140	0.190			
L	0.508	1.397	0.020	0.055			
М	27.700	29.620	1.060	1.230			
Ν	2.032	2.921	0.080	0.115			
0	0.255	0.610	0.010	0.024			
Р	5.842	6.858	0.230	0.270			



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